# **NCE N-Channel Super Trench Power MOSFET**

# **Description**

The NCEP4060EQ uses **Super Trench** technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of  $R_{DS(ON)}$  and  $Q_g$ . This device is ideal for high-frequency switching and synchronous rectification. It is ESD protested.

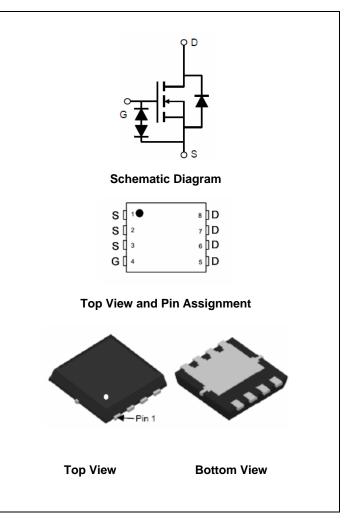
#### **General Features**

- $V_{DS}$  =40V, $I_D$  =60A  $R_{DS(ON)}$ =3.1m $\Omega$  (typical) @  $V_{GS}$ =10V  $R_{DS(ON)}$ =4.1m $\Omega$  (typical) @  $V_{GS}$ =4.5V
- Excellent gate charge x R<sub>DS(on)</sub> product(FOM)
- Very low on-resistance R<sub>DS(on)</sub>
- 150 °C operating temperature
- Pb-free lead plating
- 100% UIS tested
- ESD protection: HBM Class 2

# **Application**

- DC/DC Converter
- Ideal for high-frequency switching and synchronous rectification

100% UIS TESTED! 100% ΔVds TESTED!



## **Package Marking and Ordering Information**

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCEP4060EQ	NCEP4060EQ	DFN3.3X3.3-8L	-	-	-

## Absolute Maximum Ratings (T<sub>C</sub>=25°Cunless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>	40	V
Gate-Source Voltage	V <sub>GS</sub>	±20	V
Drain Current-Continuous (Silicon Limited)	I <sub>D</sub>	60	А
Drain Current-Continuous(T <sub>C</sub> =100°C)	I <sub>D</sub> (100℃)	42.3	А
Pulsed Drain Current (Package Limited)	I <sub>DM</sub>	260	А
Maximum Power Dissipation	P <sub>D</sub>	48	W
Derating factor		0.38	W/°C
Single pulse avalanche energy (Note 5)	E <sub>AS</sub>	288	mJ
Operating Junction and Storage Temperature Range	$T_{J}$ , $T_{STG}$	-55 To 150	$^{\circ}$



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# **Thermal Characteristic**

Thermal Resistance, Junction-to-Case <sup>(Note 2)</sup>
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Electrical Characteristics (T<sub>C</sub>=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250μA	40		-	V
Zero Gate Voltage Drain Current	ain Current I <sub>DSS</sub> V <sub>DS</sub> =40V,V <sub>GS</sub> =0V		-	-	1	μΑ
Gate-Body Leakage Current	I <sub>GSS</sub>	$V_{GS}$ =±20 $V$ , $V_{DS}$ =0 $V$	-	-	±10	μΑ
On Characteristics (Note 3)						
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ , $I_{D}=250\mu A$	1.0	1.5	2.2	V
Drain Course On Ctate Desistance	В	V <sub>GS</sub> =10V, I <sub>D</sub> =20A	-	3.1	3.4	mΩ
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =4.5V, I <sub>D</sub> =20A	-	4.1	4.4	mΩ
Forward Transconductance	<b>g</b> FS	V <sub>DS</sub> =5V,I <sub>D</sub> =20A		40	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C <sub>lss</sub>	\/ -20\/\/ -0\/	-	2100	2600	PF
Output Capacitance	Coss	$V_{DS}$ =20V, $V_{GS}$ =0V, F=1.0MHz	-	639	800	PF
Reverse Transfer Capacitance	C <sub>rss</sub>	r=1.0WIn2	-	23.6	29	PF
Switching Characteristics (Note 4)	·		•			
Turn-on Delay Time	t <sub>d(on)</sub>		-	7.5	-	nS
Turn-on Rise Time	t <sub>r</sub>	$V_{DD}$ =20 $V$ , $I_D$ =20 $A$	-	4	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =10V, $R_{G}$ =1.6 $\Omega$	-	26	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	3.3	-	nS
Total Gate Charge	Qg	V -20VI -20A	-	34.3	47	nC
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS}$ =20V, $I_{D}$ =20A, $V_{GS}$ =10V	-	7.1		nC
Gate-Drain Charge	$Q_{gd}$	V <sub>GS</sub> -10V	-	3.5		nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =60A	-		1.2	V
Diode Forward Current (Note 2)	Is		-	-	60	Α
Reverse Recovery Time	t <sub>rr</sub>	$T_J = 25^{\circ}C, I_F = I_S$	-	19	-	nS
Reverse Recovery Charge	Qrr	$di/dt = 500A/\mu s^{(Note3)}$	-	40	=	nC

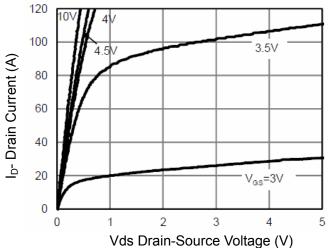
## Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- 3. Pulse Test: Pulse Width  $\leq$  300 $\mu$ s, Duty Cycle  $\leq$  2%.
- 4. Guaranteed by design, not subject to production
- 5. EAS condition : Tj=25  $^{\circ}\text{C}$  ,V\_DD=20V,V\_G=10V,L=0.5mH,Rg=25 $\Omega$

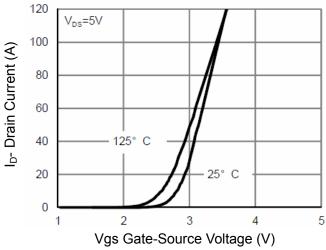
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# **Typical Electrical and Thermal Characteristics**



**Figure 1 Output Characteristics** 



**Figure 2 Transfer Characteristics** 

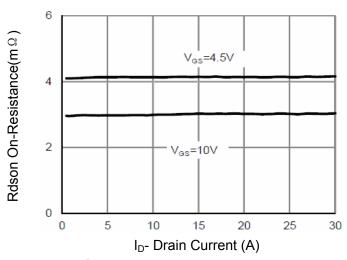
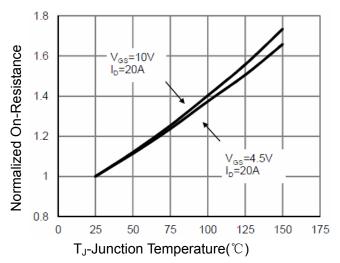


Figure 3 Rdson- Drain Current



**Figure 4 Rdson-Junction Temperature** 

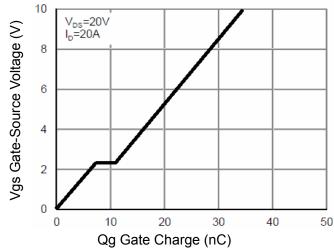


Figure 5 Gate Charge

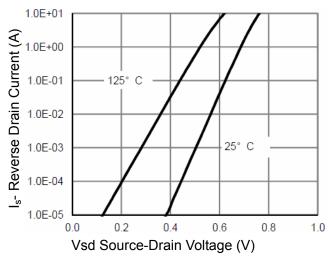


Figure 6 Source- Drain Diode Forward

# NCEP4060EQ

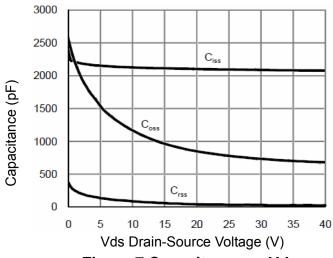


Figure 7 Capacitance vs Vds

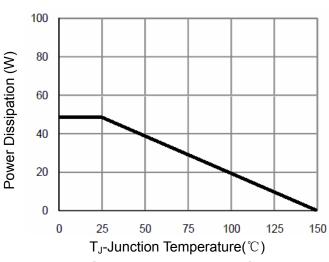
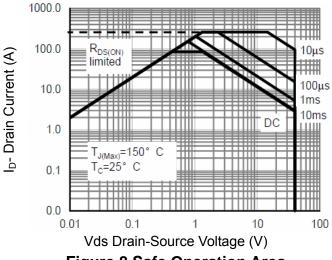


Figure 9 Power De-rating



**Figure 8 Safe Operation Area** 

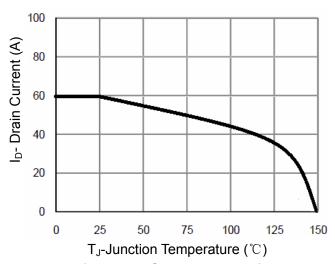
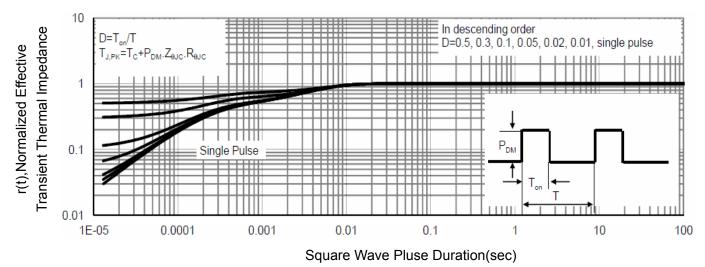


Figure 10 Current De-rating

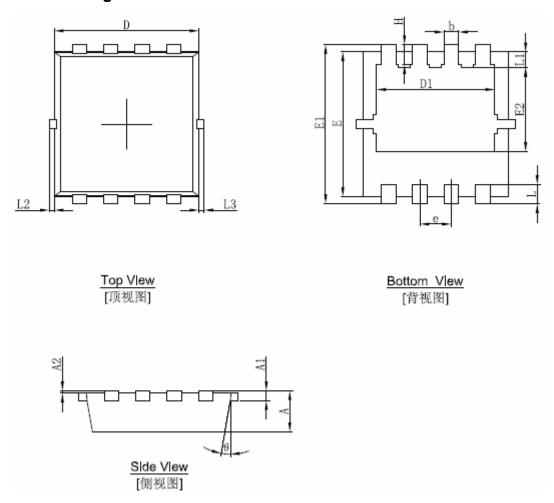


**Figure 11 Normalized Maximum Transient Thermal Impedance** 

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# **DFN3.3X3.3-8L Package Information**



Symbol	Dimensions	In Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
Α	0.650	0.850	0.026	0.033	
A1	0.152	REF.	0.006 REF.		
A2	0~0.05		0~0.002		
D	2.900	3.100	0.114	0.122	
D1	2.300	2.600	0.091	0.102	
E	2.900	3.100	0.114	0.122	
E1	3.150	3.450	0.124	0.136	
E2	1.535	1.935	0.060	0.076	
b	0.200	0.400	0.008	0.016	
е	0.550	0.750	0.022	0.030	
L	0.300	0.500	0.012	0.020	
L1	0.180	0.480	0.007	0.019	
L2	0~0.100		0~0.004		
L3	0~0	.100	0~0.004		
Н	0.315	0.515	0.012	0.020	
θ	9°	13°	9°	13°	



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